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Examiner Initials*	Cite No.1	Document Number Number-Kind Code <sup>2</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, W t Relevant Passages or Rele Figures Appear	
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Examiner Initials*	Cite No.1	Foreign Patent Document Country Code <sup>3</sup> -Number <sup>4</sup> - Kind Code <sup>5</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>6</sup>
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<sup>•</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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<sup>&</sup>lt;sup>3</sup>Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3)

For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document.

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<sup>&</sup>lt;sup>6</sup>Applicant is to place a check mark here if English language Translation is attached.

J.S. Departme	nt of Cor	nmerce, Patent and Trademark Offi	ce		Attorney Docket No.:	026-0044			
					Application No.:	10/813,837			
INFORMATION DISCLOSURE STATEMENT BY APPLICANT					Applicant(s):	Garlapati et al.			
(Use several sheets if necessary)					Filing Date:	March 31, 2004			
JUL 1 6 2004 &					Group Art Unit:	2819			
					Date Submitted:	July 14, 2004			
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			Application No.: 10/813,837						
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